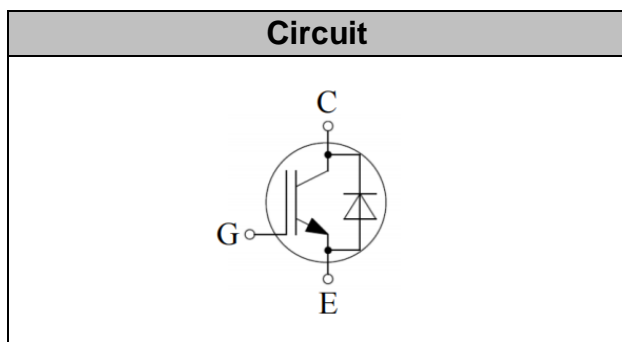


IGBT Discrete

V_{CE}	1200	V
I_C	15	A
$V_{CE(sat)} I_C=15A$	2.35	V



Applications

- Inverter for motor drive
- AC and DC servo drive amplifier
- Uninterruptible power supply

Features

- Low $V_{CE(sat)}$ Trench-FS IGBT technology
- Maximum junction temperature 175°C
- Positive temperature coefficient
- Including fast & soft recovery anti-parallel FWD
- High short circuit capability(10us)

Maximum Ratings

Parameter	Symbol	Value	Unit
Collector-Emitter Breakdown Voltage	V_{CE}	1200	V
DC Collector Current, limited by T_{jmax} $T_C=25^\circ C$ $T_C=100^\circ C$	I_C	25 15	A
Diode Forward Current, limited by T_{jmax} $T_C=25^\circ C$ $T_C=100^\circ C$	I_F	25 15	A
Continuous Gate-Emitter Voltage	V_{GE}	± 20	V
Transient Gate-Emitter Voltage ($t_p \leq 10\mu s, D < 0.010$)	V_{GE}	± 30	V
Turn off Safe Operating Area $V_{CE} \leq 1200V$, $T_j \leq 150^\circ C$		60	A
Pulsed Collector Current, $V_{GE}=15V$, t_p limited by T_{jmax}	I_{CM}	60	A
Diode Pulsed Current, t_p limited by T_{jmax}	I_{Fpuls}	60	A
Short Circuit Withstand Time, $V_{GE}=15V, V_{CC}=900V, V_{CEM} \leq 1200V$	T_{sc}	10	μs
Power Dissipation, $T_j=175^\circ C, T_C=25^\circ C$	P_{tot}	157	W



Operating Junction Temperature	T_j	-40...+175	°C
Storage Temperature	T_s	-55...+150	°C
Soldering Temperature, wave soldering 1.6mm (0.063in.) from case for 10s		260	°C

Electrical Characteristics of the IGBT ($T_j = 25^\circ\text{C}$ unless otherwise specified):

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Static						
Collector-Emitter Breakdown Voltage	BV_{CES}	$V_{GE}=0V, I_C=250\mu A$	1200		-	V
Gate Threshold Voltage	$V_{GE(th)}$	$V_{GE}=V_{CE}, I_C=400\mu A$	5.2	5.8	6.4	V
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$V_{GE}=15V, I_C=15A$ $T_j=25^\circ\text{C}$, $T_j=125^\circ\text{C}$ $T_j=150^\circ\text{C}$		2.35 2.95 3.25	2.75	V
Zero Gate Voltage Collector Current	I_{CES}	$V_{CE}=1200V, V_{GE}=0V$ $T_j=25^\circ\text{C}$, $T_j=150^\circ\text{C}$			0.25 5.00	mA
Gate-Emitter Leakage Current	I_{GES}	$V_{CE}=0V, V_{GE}=\pm 20V$			400	nA

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Dynamic						
Input Capacitance	C_{ies}	$V_{CE}=25V, V_{GE}=0V,$ $f=1\text{MHz}$	-	0.68	-	nF
Reverse Transfer Capacitance	C_{res}		-	0.02	-	
Gate Charge	Q_G	$V_{CC}=960V, I_C=15A,$ $V_{GE}=15V$	-	0.08	-	uC
Short Circuit Collector Current	I_{SC}	$V_{GE}=15V, t_{sc}\leq 10\mu s,$ $V_{CC}=900V, T_j\leq 150^\circ\text{C}$	-	50	-	A

**Electrical Characteristics of the Diode** ($T_j = 25^\circ\text{C}$ unless otherwise specified):

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Static						
Diode Forward Voltage	V_F	$I_F = 15\text{A}$ $T_j = 25^\circ\text{C}$, $T_j = 125^\circ\text{C}$ $T_j = 150^\circ\text{C}$		2.40 2.25 2.15	2.90	V

Switching Characteristic, Inductive Load

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Dynamic , at $T_j = 25^\circ\text{C}$						
Turn-on Delay Time	$t_{d(on)}$	$V_{CC} = 600\text{V}$, $I_C = 15\text{A}$, $V_{GE} = -5\text{V} \sim 15\text{V}$, $R_g = 51\ \Omega$	-	14	-	ns
Rise Time	t_r		-	36	-	ns
Turn-on Energy	E_{on}		-	2.25	-	mJ
Turn-off Delay Time	$t_{d(off)}$		-	58	-	ns
Fall Time	t_f		-	263	-	ns
Turn-off Energy	E_{off}		-	0.82	-	mJ
Dynamic , at $T_j = 125^\circ\text{C}$						
Turn-on Delay Time	$t_{d(on)}$	$V_{CC} = 600\text{V}$, $I_C = 15\text{A}$, $V_{GE} = -5\text{V} \sim 15\text{V}$, $R_g = 51\ \Omega$	-	13	-	ns
Rise Time	t_r		-	37	-	ns
Turn-on Energy	E_{on}		-	2.64	-	mJ
Turn-off Delay Time	$t_{d(off)}$		-	63	-	ns
Fall Time	t_f		-	378	-	ns
Turn-off Energy	E_{off}		-	1.18	-	mJ
Dynamic , at $T_j = 150^\circ\text{C}$						
Turn-on Delay Time	$t_{d(on)}$	$V_{CC} = 600\text{V}$, $I_C = 15\text{A}$, $V_{GE} = -5\text{V} \sim 15\text{V}$, $R_g = 51\ \Omega$	-	13	-	ns
Rise Time	t_r		-	39	-	ns
Turn-on Energy	E_{on}		-	2.81	-	mJ
Turn-off Delay Time	$t_{d(off)}$		-	65	-	ns
Fall Time	t_f		-	412	-	ns
Turn-off Energy	E_{off}		-	1.33	-	mJ

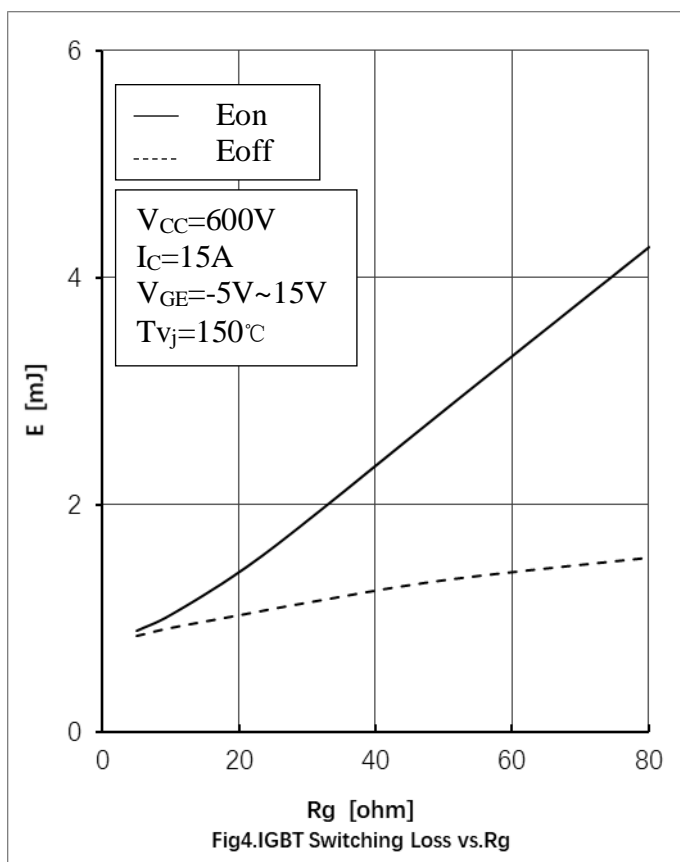
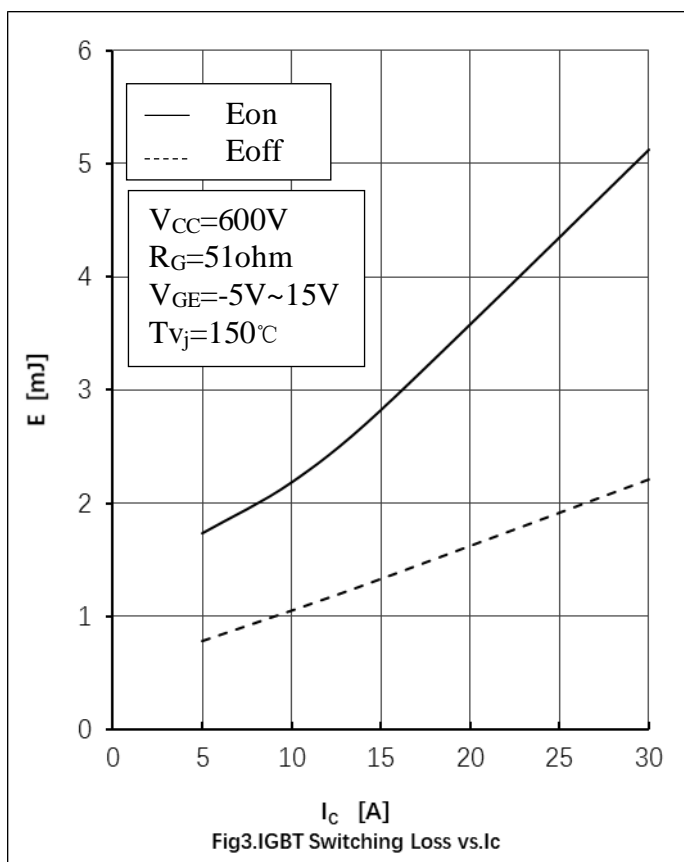
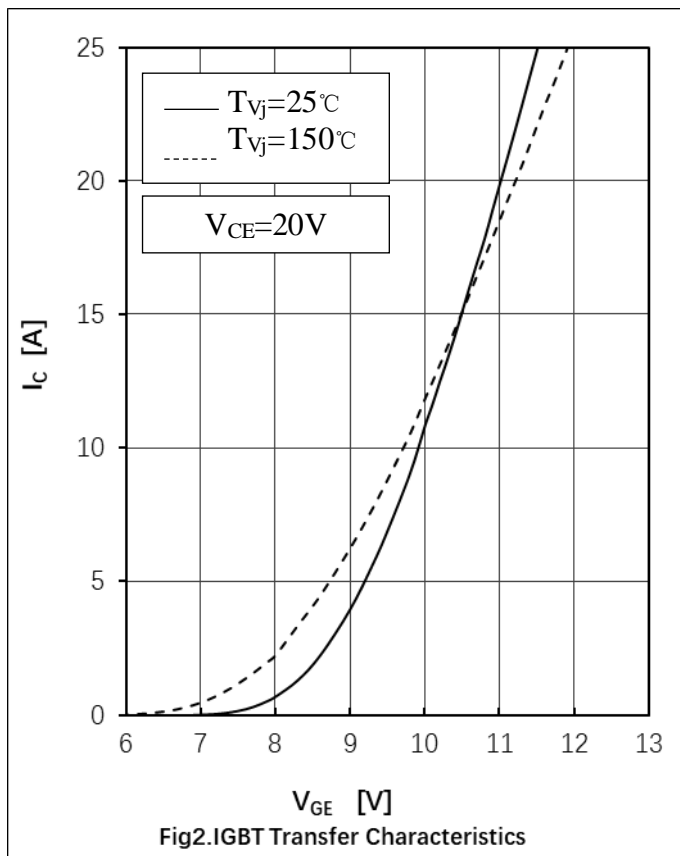
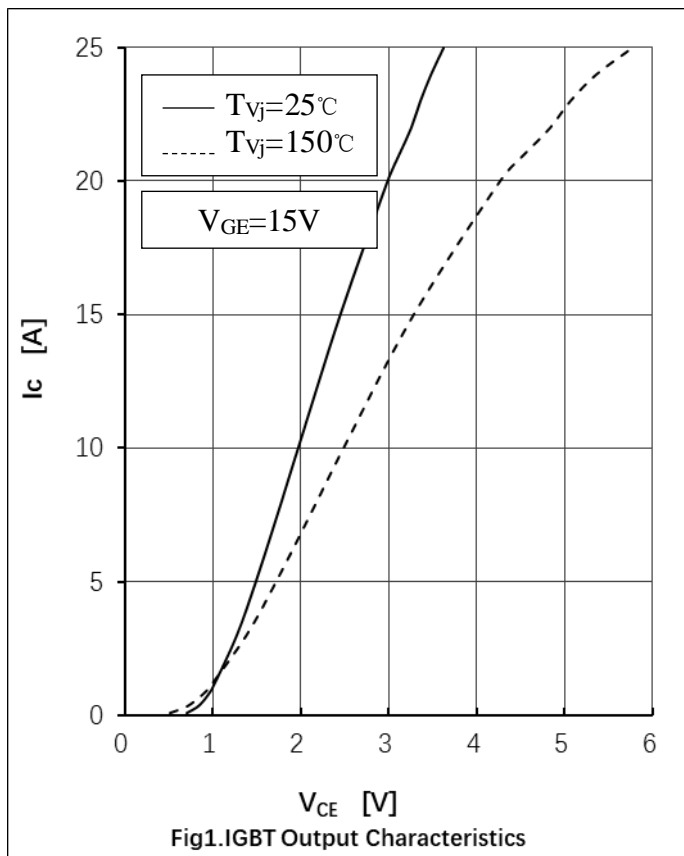


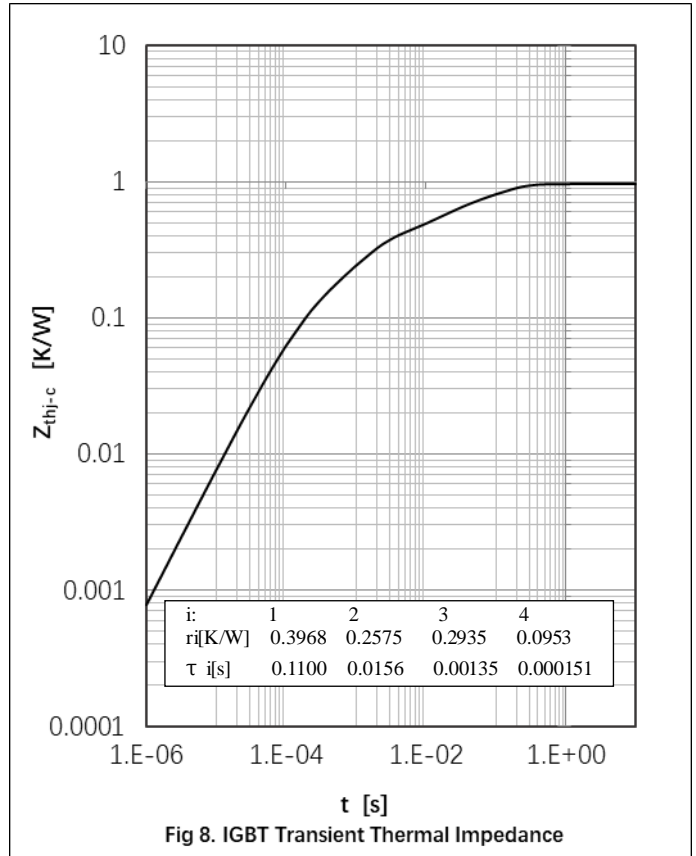
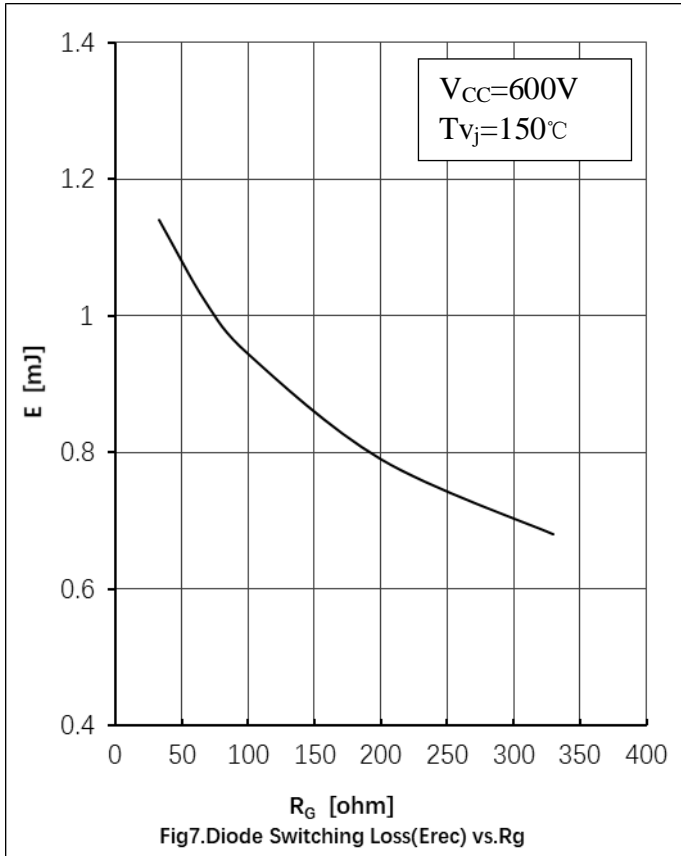
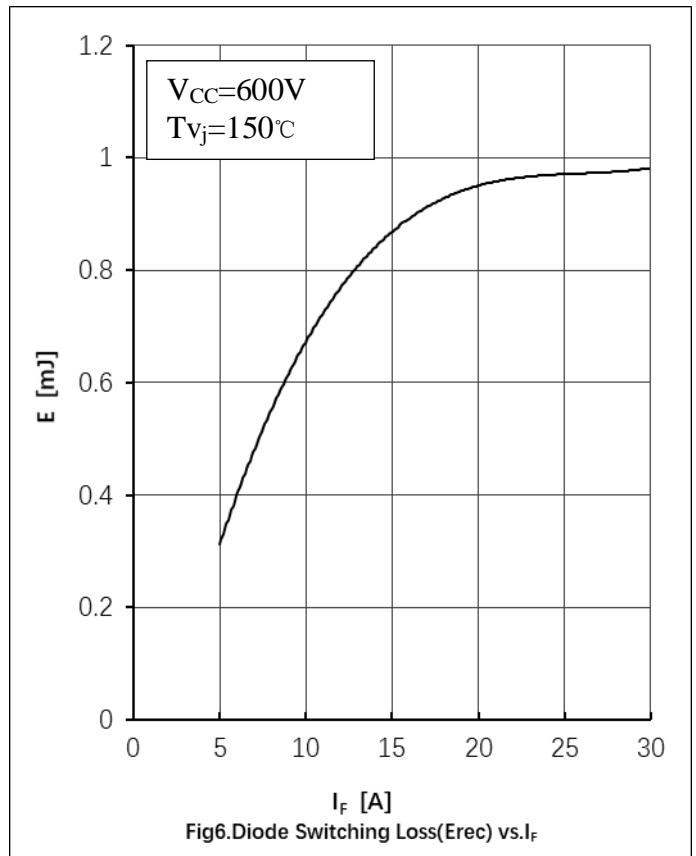
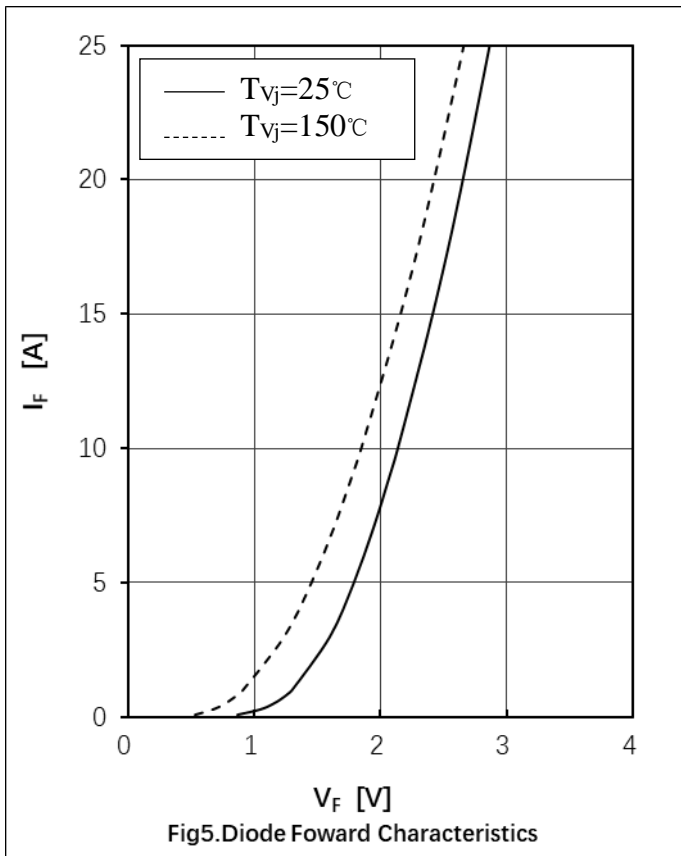
Electrical Characteristics of the DIODE

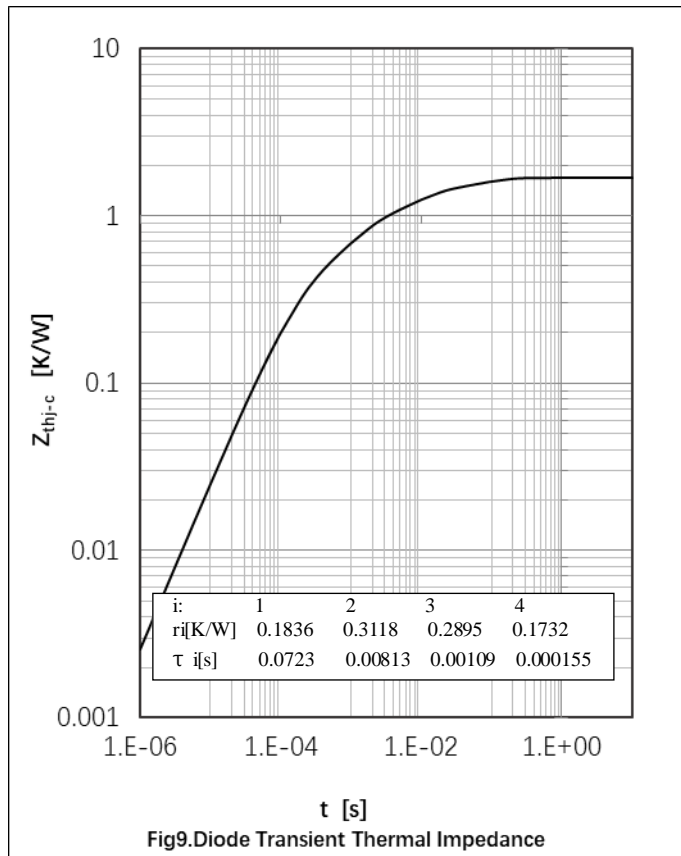
Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Dynamic , at T_j= 25°C						
Reverse Recovery Current	I _{rr}	I _F =15A, V _R =600V, -di/dt=500A/μs,	-	8	-	A
Reverse Recovery Charge	Q _{rr}		-	1.2	-	uC
Reverse Recovery Energy	E _{rec}		-	0.7	-	mJ
Dynamic , at T_j= 125°C						
Reverse Recovery Current	I _{rr}	I _F =15A, V _R =600V, -di/dt=500A/μs,	-	11	-	A
Reverse Recovery Charge	Q _{rr}		-	1.9	-	uC
Reverse Recovery Energy	E _{rec}		-	1.0	-	mJ
Dynamic , at T_j= 150°C						
Reverse Recovery Current	I _{rr}	I _F =15A, V _R =600V, -di/dt=500A/μs,	-	12	-	A
Reverse Recovery Charge	Q _{rr}		-	2.2	-	uC
Reverse Recovery Energy	E _{rec}		-	1.1	-	mJ

Thermal Resistance

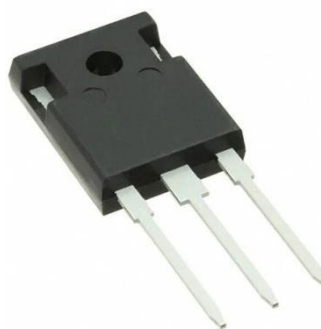
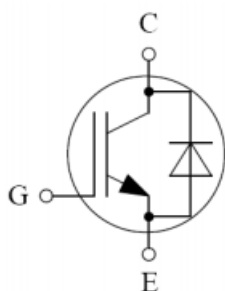
Parameter	Symbol	Max. Value	Unit
IGBT Thermal Resistance, Junction - Case	R _{th(j-c)}	0.95	K/W
Diode Thermal Resistance, Junction - Case	R _{th(j-c)}	1.70	K/W
Thermal Resistance, Junction - Ambient	R _{th(j-a)}	40	K/W





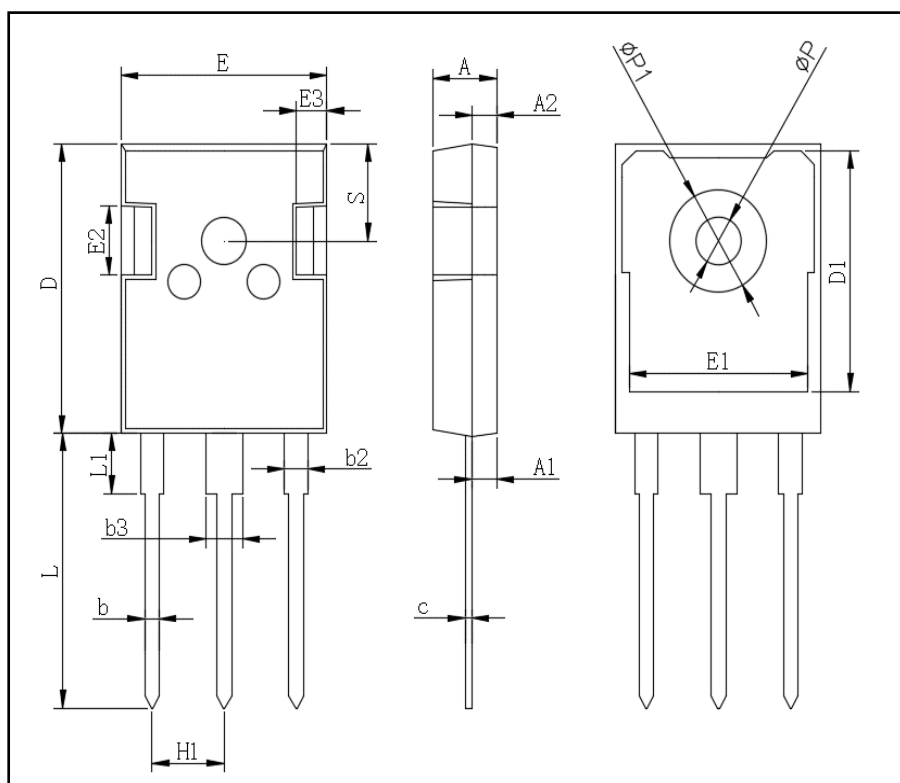


● **Circuit Diagram**



● **Package Outline Information**

CASE: TO 247



TO-247AB		
Dim	Min	Max
A	4.80	5.20
A1	2.21	2.61
A2	1.85	2.15
b	1.0	1.4
b2	1.91	2.21
C	0.5	0.7
D	20.70	21.30
D1	16.25	16.85
E	15.50	16.10
E1	13.0	13.6
E2	4.80	5.20
E3	2.30	2.70
L	19.62	20.22
L1	-	4.30
ΦP	3.40	3.80
$\Phi P1$	-	7.30
S	6.15TYP	
H1	5.44TYP	
b3	2.80	3.20



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